

CT60AM-18F

Insulated Gate Bipolar Transistor

REJ03G1374-0200

(Previous: MEJ02G0023-0101) Rev.2.00

Jul 07, 2006

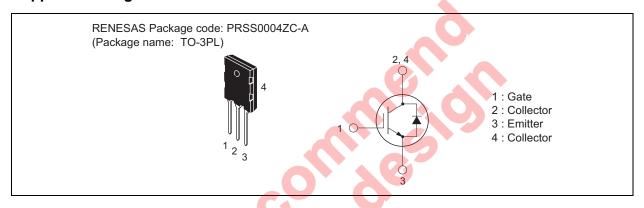
Features

V_{CES}: 900 V

• $I_C: 60 A$

• Integrated fast-recovery diode

Appearance Figure



Applications

Microwave oven, Electromagnetic cooking devices, Rice-cookers

Maximum Ratings

 $(Tc = 25^{\circ}C)$

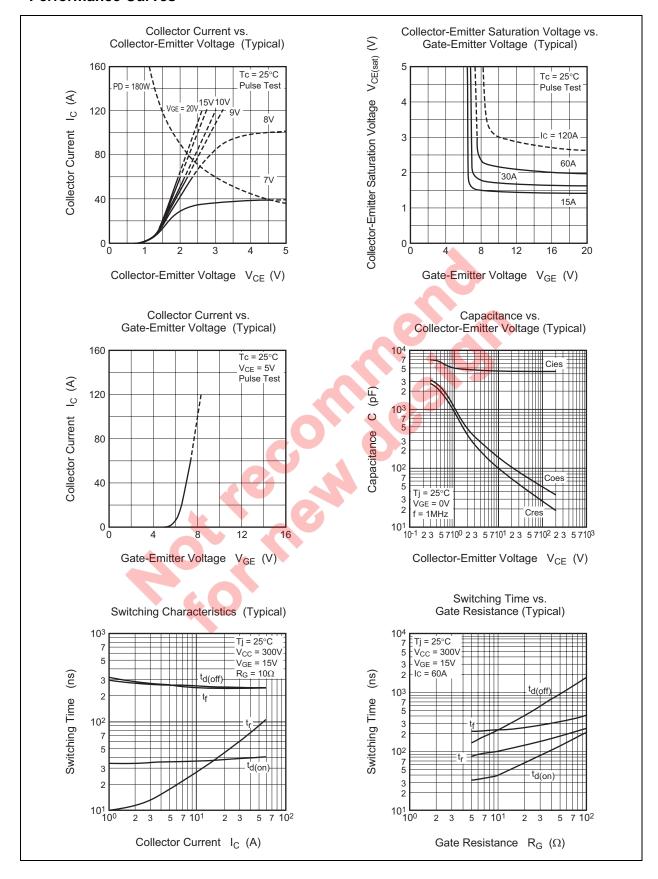
Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	V _{CES}	900	V	V _{GE} = 0 V
Gate-emitter voltage	V_{GES}	±25	V	
Peak gate-emitter voltage	V_{GEM}	±30	V	
Collector current	Ic	60	Α	
Collector current (Pulse)	I _{CM}	120	Α	
Emitter current	I _E	40	Α	
Maximum power dissipation	Pc	180	W	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	

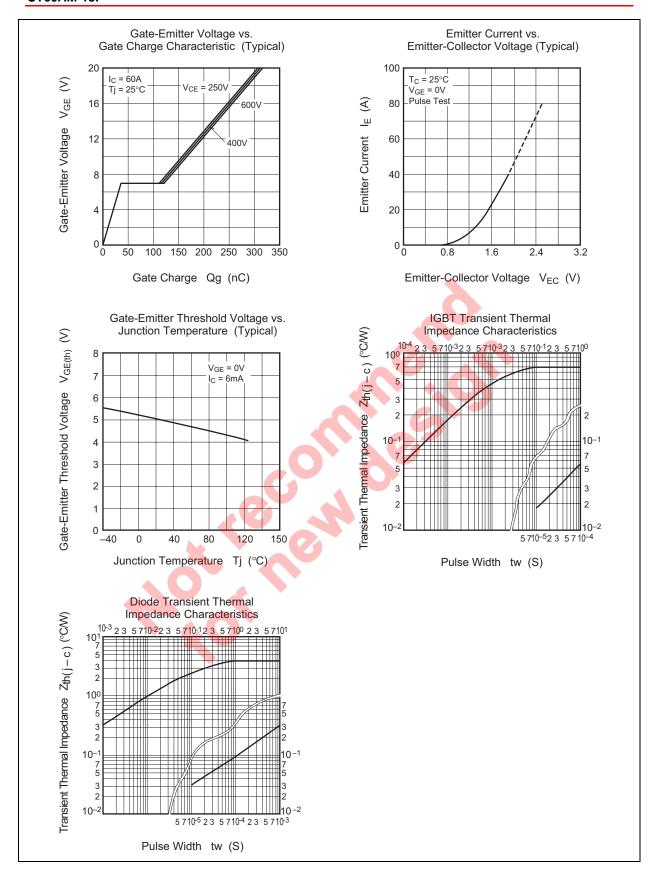
Electrical Characteristics

 $(Tch = 25^{\circ}C)$

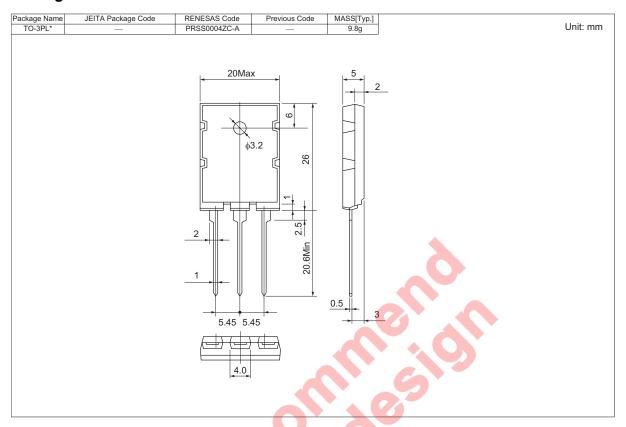
	Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Collector-emitter leakage current	I _{CES}	_	_	1	mA	$V_{CE} = 900 \text{ V}, V_{GE} = 0 \text{ V}$
	Gate-emitter leakage current	I _{GES}		_	0.5	μΑ	$V_{GE} = \pm 20 \text{ V}, V_{CE} = 0 \text{ V}$
	Gate-emitter threshold voltage		2.0	4.0	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 6 \text{ mA}$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Collector-emitter saturation voltage		_	2.1	2.7	V	I _C = 60 A, V _{CE} = 15 V
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Input capacitance	Cies	_	4400	_	pF	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V},$
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Output capacitance	Coes	_	115	_	pF	f = 1 MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Reverse transfer capacitance	Cres	_	75	_	pF	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Turn-on delay time	t _{d (on)}	_	0.05	_	μs	$V_{CC} = 300 \text{ V}, I_{C} = 60 \text{ A},$
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Turn-on Rise time	t _r	_	0.1	_	μs	V_{GE} = 15 V, R_{G} = 10 Ω
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Turn-off delay time	t _{d (off)}	_	0.2	_	μs	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Turn-off Fall time	t _f	_	0.3	_	μs	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Tail loss	E _{tail}	_	0.6	1.0	mJ/pls	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Tail current	I _{tail}	_	6.0	12	A	αγιατ – 200 ν/μ3
Thermal resistance (IGBT)	Emitter-collector voltage	V_{EC}		2.2	3.0	V	I _E = 60 A, V _{GE} = 0 V
Thermal resistance (Diode) R _{th (j-c)} — — 4.0 °C/W Junction to case	Diode reverse recovery time	t _{rr}	_	0.5	2.0	μs	$I_E = 60 \text{ A}, d_{iS}/d_t = -20 \text{ A}/\mu\text{s}$
Thermal resistance (Diode) R _{th (j-c)} — — 4.0 °C/W Junction to case	Thermal resistance (IGBT)	R _{th (j-c)}	_	_	0.69	°C/W	Junction to case
	Thermal resistance (Diode)		_		4.0	°C/W	Junction to case

Performance Curves





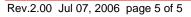
Package Dimensions



Ordering Information

Lead form	Standard packing	Quar	ntity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)		25	Type name	CT60AM-18F
Lead form	Plastic Magazine (Tube)		25	Type name – Lead forming code	CT60AM-18F-AD

Note: Please confirm the specification about the shipping in detail.



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